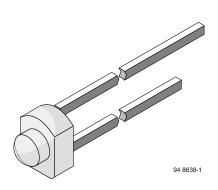
GREEN (5-2008)**



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Silicon NPN Phototransistor

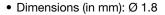


DESCRIPTION

BPW17N is a silicon NPN phototransistor with high radiant sensitivity in clear, T-3/4 plastic package with lens. It is sensitive to visible and near infrared radiation. On PCB this package size enables assembly of arrays with 2.54 mm pitch.

FEATURES

Package type: leaded
Package form: T-¾



· High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

• Fast response times

• Angle of half sensitivity: $\varphi = \pm 12^{\circ}$

 Comliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

Detector in electronic control and drive circuits

| PRODUCT SUMMARY | | | |
|-----------------|----------------------|---------|-----------------------|
| COMPONENT | I _{ca} (mA) | φ (deg) | λ _{0.1} (nm) |
| BPW17N | 1.0 | ± 12 | 450 to 1040 |

Note

• Test condition see table "Basic Characteristics"

| ORDERING INFORMATION | | | | |
|----------------------|-----------|------------------------------|--------------|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | |
| BPW17N | Bulk | MOQ: 5000 pcs, 5000 pcs/bulk | T-¾ | |

Note

· MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | |
|---|--|-------------------|---------------|------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Collector emitter voltage | | V _{CEO} | 32 | V |
| Emitter collector voltage | | V _{ECO} | 5 | V |
| Collector current | | I _C | 50 | mA |
| Collector peak current | $t_p/T = 0.5, t_p \le 10 \text{ ms}$ | I _{CM} | 100 | mA |
| Power dissipation | T _{amb} ≤ 55 °C | P _V | 100 | mW |
| Junction temperature | | Tj | 100 | °C |
| Operating temperature range | | T _{amb} | - 40 to + 100 | °C |
| Storage temperature range | | T _{stg} | - 40 to + 100 | °C |
| Soldering temperature | t ≤ 3 s | T _{sd} | 260 | °C |
| Thermal resistance junction/ambient | Connected with Cu wire, 0.14 mm ² | R _{thJA} | 450 | K/W |



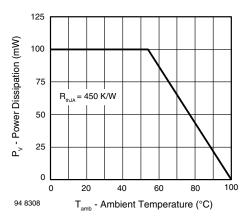
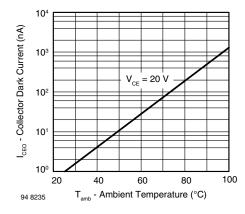
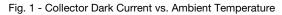


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|---|----------------------|------|-------------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Collector emitter breakdown voltage | I _C = 1 mA | V _{(BR)CEO} | 32 | | | V |
| Collector emitter dark current | $V_{CE} = 20 \text{ V}, E = 0$ | I _{CEO} | | 1 | 200 | nA |
| Collector emitter capacitance | V _{CE} = 5 V, f = 1 MHz, E = 0 | C _{CEO} | | 8 | | pF |
| Collector light current | E_e = 1 mW/cm ² , λ = 950 nm, V_{CE} = 5 V | I _{ca} | 0.5 | 1.0 | | mA |
| Angle of half sensitivity | | φ | | ± 12 | | deg |
| Wavelength of peak sensitivity | | λ_{p} | | 825 | | nm |
| Range of spectral bandwidth | | λ _{0.1} | | 450 to 1040 | | nm |
| Collector emitter saturation voltage | E_e = 1 mW/cm ² , λ = 950 nm, I_C = 0.1 mA | V _{CEsat} | | | 0.3 | V |
| Turn-on time | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | t _{on} | | 4.8 | | μs |
| Turn-off time | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | t _{off} | | 5.0 | | μs |
| Cut-off frequency | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | f _c | | 120 | | kHz |

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)





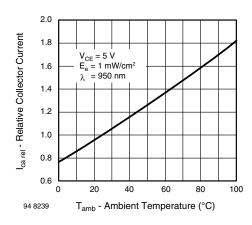


Fig. 2 - Relative Collector Current vs. Ambient Temperature

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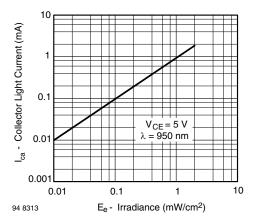


Fig. 3 - Collector Light Current vs. Irradiance

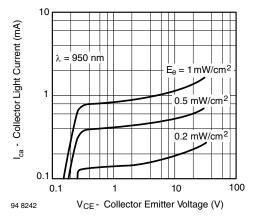


Fig. 4 - Collector Light Current vs. Collector Emitter Voltage

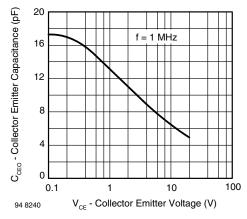


Fig. 5 - Collector Emitter Capacitance vs. Collector Emitter Voltage

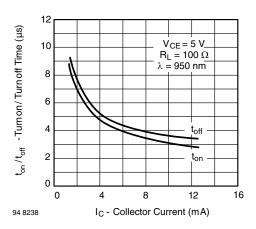


Fig. 6 - Turn-on/Turn-off Time vs. Collector Current

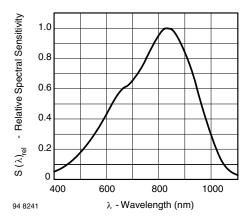


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

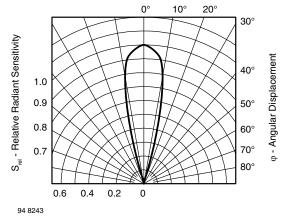
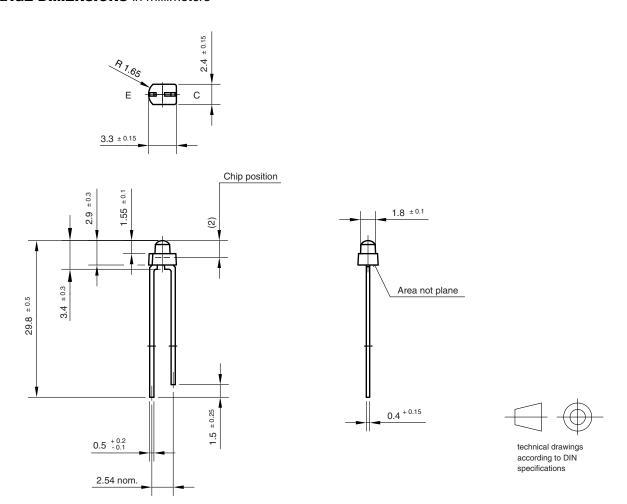


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement

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PACKAGE DIMENSIONS in millimeters



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